

TDSEMIC

拓電半導體

自主封測 品質把控 售後保障

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電源管理



顯示驅動



二三極管



LDO穩壓器



觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

GBP610-TD

產品規格說明書

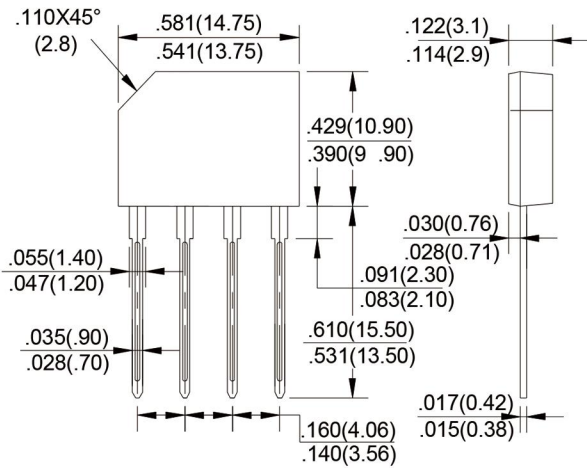
GLASS PASSIVATED BRIDGE RECTIFIERS		REVERSE VOLTAGE - 50 to 1000Volts FORWARD CURRENT - 6.0 Amperes																																																																																																																					
FEATURES ● Surge overload rating - 60 amperes peak ● Ideal for printed circuit board ● Plastic material has underwriters laboratory flammability classification 94V-0 ● Mounting position: Any		GBP  Dimensions in inches and (millimeters)																																																																																																																					
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave ,60Hz, resistive or inductive load. For capacitive load, derate current by 20% <table><tr><th>CHARACTERISTICS</th><th>SYMBOL</th><th>GBP 6005</th><th>GBP 601</th><th>GBP 602</th><th>GBP 604</th><th>GBP 606</th><th>GBP 608</th><th>GBP 610</th><th>UNIT</th></tr><tr><td>Maximum Recurrent Peak Reverse Voltage</td><td>V_{RRM}</td><td>50</td><td>100</td><td>200</td><td>400</td><td>600</td><td>800</td><td>1000</td><td>V</td></tr><tr><td>Maximum RMS Bridge Input Voltage</td><td>V_{RMS}</td><td>30</td><td>70</td><td>140</td><td>280</td><td>420</td><td>560</td><td>700</td><td>V</td></tr><tr><td>Maximum DC Blocking Voltage</td><td>V_{DC}</td><td>50</td><td>100</td><td>200</td><td>400</td><td>600</td><td>800</td><td>1000</td><td>V</td></tr><tr><td>Maximum Average Forward Rectified Output Current @ TA=50°C</td><td>I_(AV)</td><td colspan="7">6.0</td><td>A</td></tr><tr><td>Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load</td><td>I_{FSM}</td><td colspan="7">60</td><td>A</td></tr><tr><td>Maximum Forward Voltage Drop Per Bridge Element at 2.0A Peak</td><td>V_F</td><td colspan="7">1.1</td><td>V</td></tr><tr><td>Maximum Reverse Current at Rated DC Blocking Voltage Per Element</td><td>I_R</td><td colspan="7">10.0</td><td>uA</td></tr><tr><td>Maximum Reverse Current at Rated DC Blocking Voltage Per Element TA=100°C</td><td>I_R</td><td colspan="7">1.0</td><td>mA</td></tr><tr><td>Operating Temperature Range</td><td>T_J</td><td colspan="7">-55 to +150</td><td>°C</td></tr><tr><td>Storage Temperature Range</td><td>T_{STG}</td><td colspan="7">-55 to +150</td><td>°C</td></tr></table>										CHARACTERISTICS	SYMBOL	GBP 6005	GBP 601	GBP 602	GBP 604	GBP 606	GBP 608	GBP 610	UNIT	Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V	Maximum RMS Bridge Input Voltage	V _{RMS}	30	70	140	280	420	560	700	V	Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V	Maximum Average Forward Rectified Output Current @ TA=50°C	I _(AV)	6.0							A	Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load	I _{FSM}	60							A	Maximum Forward Voltage Drop Per Bridge Element at 2.0A Peak	V _F	1.1							V	Maximum Reverse Current at Rated DC Blocking Voltage Per Element	I _R	10.0							uA	Maximum Reverse Current at Rated DC Blocking Voltage Per Element TA=100°C	I _R	1.0							mA	Operating Temperature Range	T _J	-55 to +150							°C	Storage Temperature Range	T _{STG}	-55 to +150							°C
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FIG.1-FORWARD CURRENT DERATING CURVE

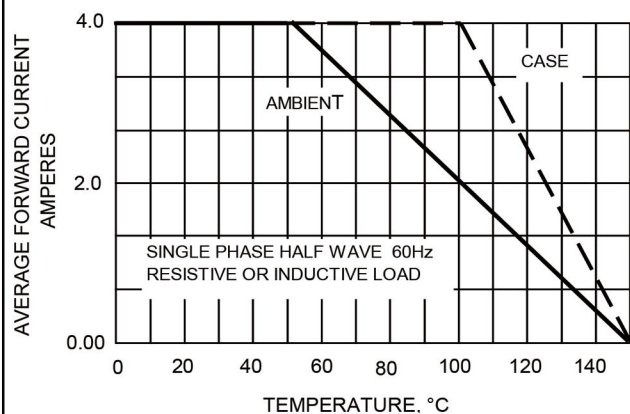


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

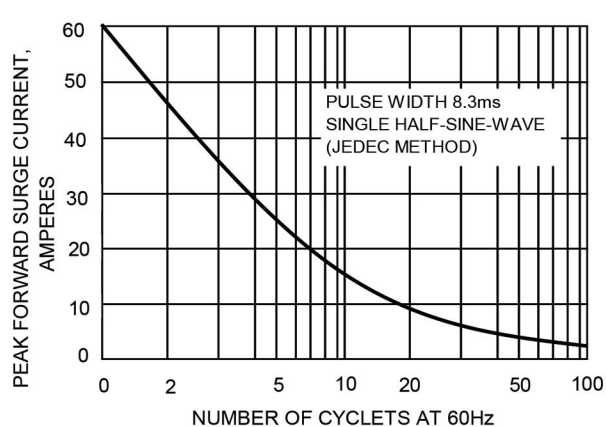


FIG.3-TYPICAL JUNCTION CAPACITANCE

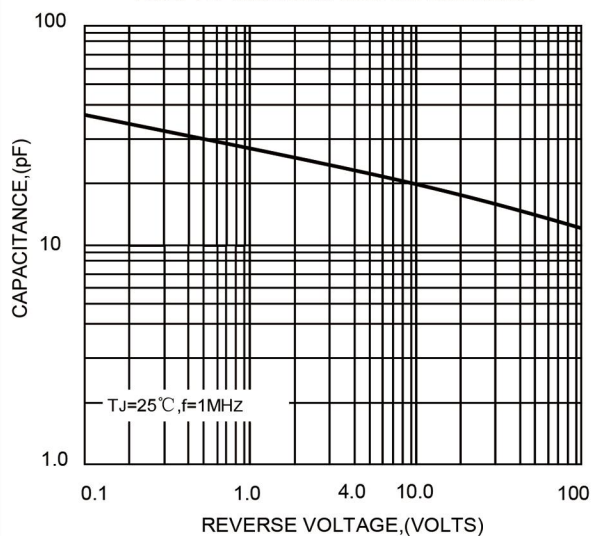


FIG.4-TYPICAL FORWARD CHARACTERISTICS

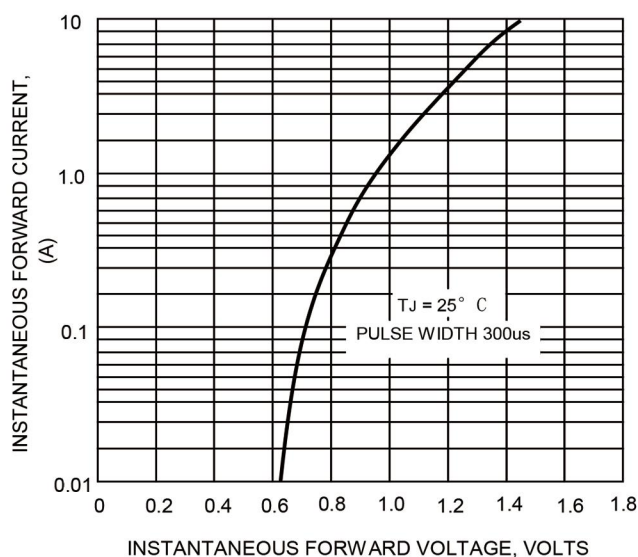


FIG.5-TYPICAL REVERSE CHARACTERISTICS

